

DM74AS10 Triple 3-Input NAND Gate

Features

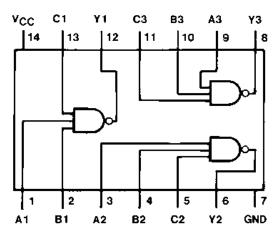
- Switching specifications at 50pF
- Switching specifications guaranteed over full temperature and V_{CC} range
- Advanced oxide-isolated, ion-implanted Schottky TTL process
- Functionally and pin for pin compatible with Schottky, low power Schottky, and advanced low power Schottky TTL counterpart
- Improved AC performance over Schottky, low power Schottky, and advanced low power Schottky counterparts

Ordering Information

Order Number	Package Number	Package Description
DM74AS10M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering number.

Connection Diagram



Function Table

General Description

which performs the logic NAND function.

This device contains three independent gates, each of

 $\mathbf{Y} = \overline{\mathbf{ABC}}$

	Output		
Α	В	С	Y
Х	Х	L	Н
Х	L	Х	Н
L	Х	Х	Н
Н	Н	Н	L

H = HIGH Logic Level

L = LOW Logic Level

X = Either LOW or HIGH Logic Level



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating		
V _{CC}	Supply Voltage	7V		
VI	Input Voltage	7V		
T _A	Operating Free Air Temperature Range	0°C to +70°C		
T _{STG}	Storage Temperature Range	–65°C to +150°C		
θ _{JA}	Typical Thermal Resistance	114.0°C/W		

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Nom.	Max.	Units
V _{CC}	Supply Voltage	4.5	5	5.5	V
V _{IH}	HIGH Level Input Voltage	2			V
V _{IL}	LOW Level Input Voltage			0.8	V
I _{OH}	HIGH Level Output Current			-2	mA
I _{OL}	LOW Level Output Current			20	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

Over recommended operating free air temperature range. All typical values are measured at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Units
V _{IK}	Input Clamp Voltage	$V_{CC} = 4.5V, I_{I} = -18mA$				-1.2	V
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -2mA$, $V_{CC} = 4.5V$ to 5.5V		$V_{CC} - 2$			V
V _{OL}	LOW Level Output Voltage	$V_{CC} = 4.5 V, I_{O}$	_L = 20 mA		0.35	0.5	V
I _I	Input Current @ Max Input Voltage	$V_{CC} = 5.5 V, V_{II}$	_H = 7V			0.1	mA
I _{IH}	HIGH Level Input Current	$V_{CC} = 5.5V, V_{IH} = 2.7V$				20	μA
I _{IL}	LOW Level Input Current	$V_{CC} = 5.5 V, V_{II}$	L = 0.4V			-0.5	mA
Ι _Ο	Output Drive Current	$V_{CC} = 5.5 V, V_{C}$	_D = 2.25V	-30		-112	mA
I _{CC}	Supply Current	$V_{CC} = 5.5V$	Outputs HIGH		1.5	2.4	mA
			Outputs LOW		8.1	13	

Switching Characteristics

Over recommended operating free air temperature range.

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time, LOW-to-HIGH Level Output	$V_{CC} = 4.5V \text{ to } 5.5V$ R _L = 500 Ω , C _L = 50pF	1	4.5	ns
t _{PHL}	Propagation Delay Time, HIGH-to-LOW Level Output		1	4.5	ns

Physical Dimensions Dimensions are in millimeters unless otherwise noted.

